

# RJK03E2DNS

## Silicon N Channel Power MOS FET Power Switching

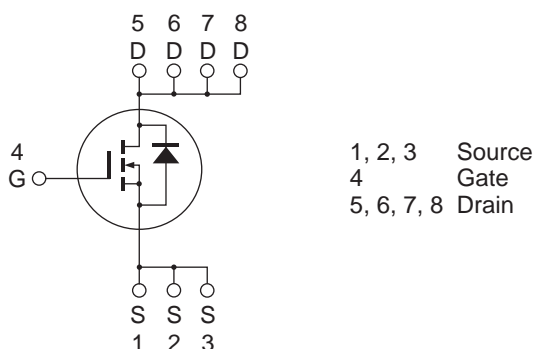
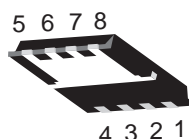
R07DS0658EJ0300  
(Previous: REJ03G1904-0200)  
Rev.3.00  
Feb 01, 2012

### Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance  
 $R_{DS(on)} = 6.9 \text{ m}\Omega$  typ. (at  $V_{GS} = 10 \text{ V}$ )
- Pb-free
- Halogen-free

### Outline

RENESAS Package code: PWSN0008JB-A  
(Package name: HWSN-8)



### Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	30	V
Gate to source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	$I_D$	16	A
Drain peak current	$I_{D(pulse)}$ <sup>Note 1</sup>	64	A
Body-drain diode reverse drain current	$I_{DR}$	16	A
Avalanche current	$I_{AP}$ <sup>Note 2</sup>	8	A
Avalanche energy	$E_{AR}$ <sup>Note 2</sup>	6.4	mJ
Channel dissipation	$P_{ch}$ <sup>Note 3</sup>	12.5	W
Channel to case thermal impedance	$\theta_{ch-c}$ <sup>Note 3</sup>	10.0	$^\circ\text{C/W}$
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

Notes: 1.  $PW \leq 10 \mu\text{s}$ , duty cycle  $\leq 1\%$   
2. Value at  $T_{ch} = 25^\circ\text{C}$ ,  $R_g \geq 50 \Omega$   
3.  $T_c = 25^\circ\text{C}$

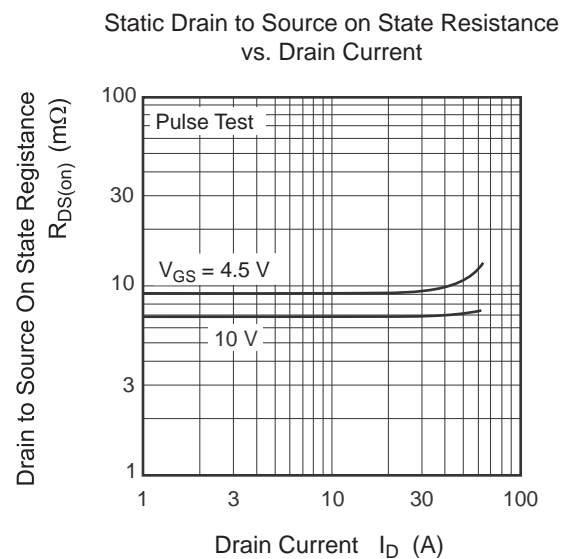
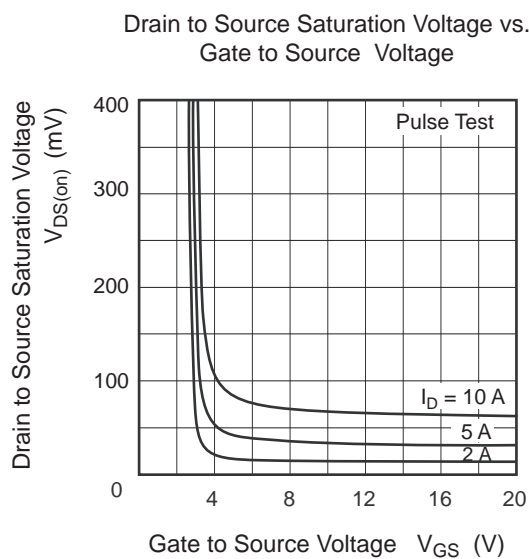
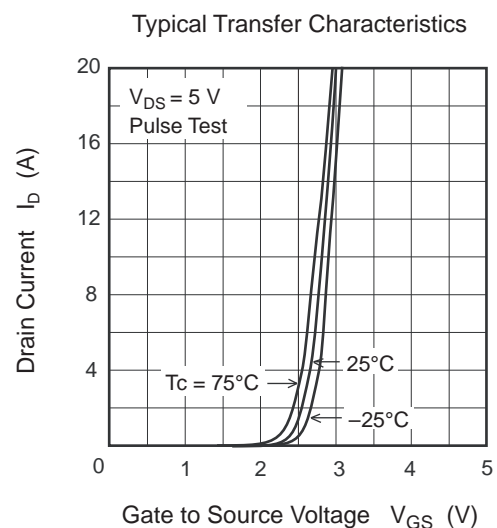
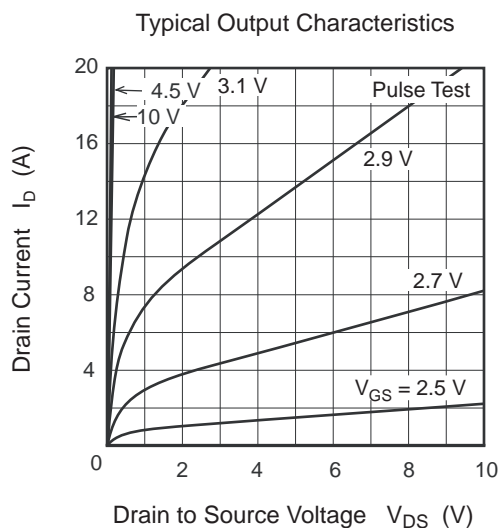
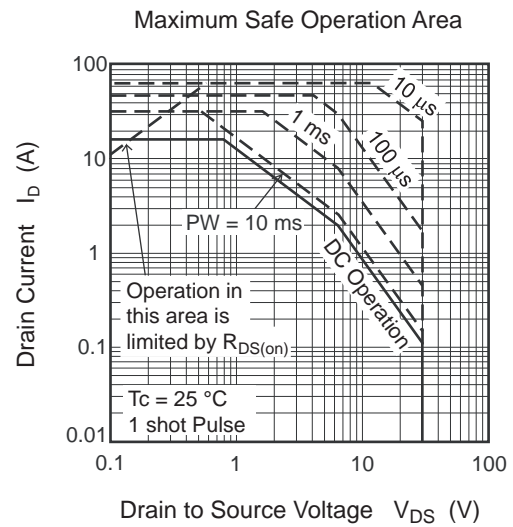
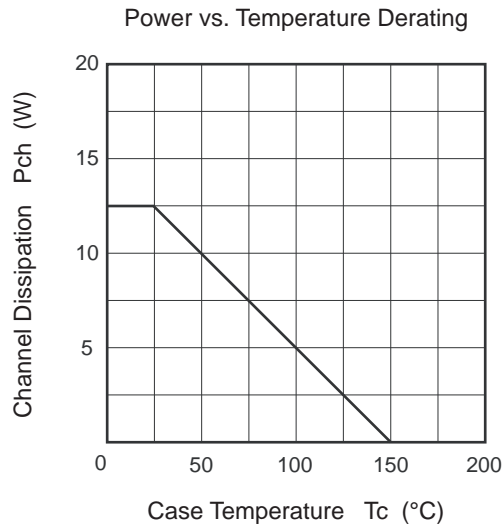
## Electrical Characteristics

(Ta = 25°C)

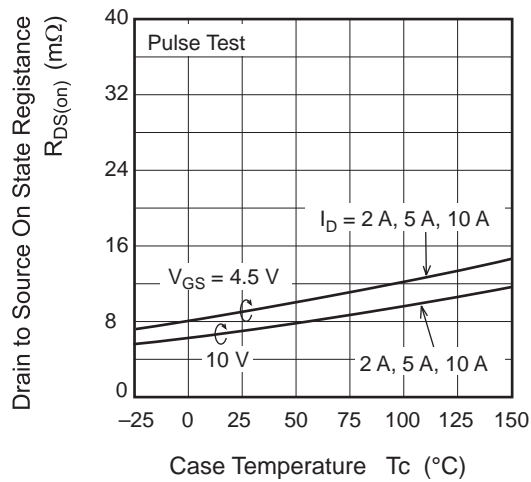
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 20 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 30 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	6.9	9.0	$\text{m}\Omega$	$I_D = 8 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note4</sup>
	$R_{DS(on)}$	—	9.1	12.7	$\text{m}\Omega$	$I_D = 8 \text{ A}$ , $V_{GS} = 4.5 \text{ V}$ <sup>Note4</sup>
Forward transfer admittance	$ y_{fs} $	—	33	—	S	$I_D = 8 \text{ A}$ , $V_{DS} = 5 \text{ V}$ <sup>Note4</sup>
Input capacitance	$C_{iss}$	—	1100	1540	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	$C_{oss}$	—	157	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	$C_{rss}$	—	78	—	pF	$f = 1 \text{ MHz}$
Gate Resistance	$R_g$	—	1.2	2.4	$\Omega$	
Total gate charge	$Q_g$	—	7.3	—	nC	$V_{DD} = 10 \text{ V}$
Gate to source charge	$Q_{gs}$	—	3.1	—	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	1.8	—	nC	$I_D = 16 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	8.6	—	ns	$V_{GS} = 10 \text{ V}$ , $I_D = 8 \text{ A}$
Rise time	$t_r$	—	3.9	—	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	33	—	ns	$R_L = 1.25 \Omega$
Fall time	$t_f$	—	4.7	—	ns	$R_g = 4.7 \Omega$
Body-drain diode forward voltage	$V_{DF}$	—	0.82	1.07	V	$I_F = 16 \text{ A}$ , $V_{GS} = 0$ <sup>Note4</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	13	—	ns	$I_F = 16 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

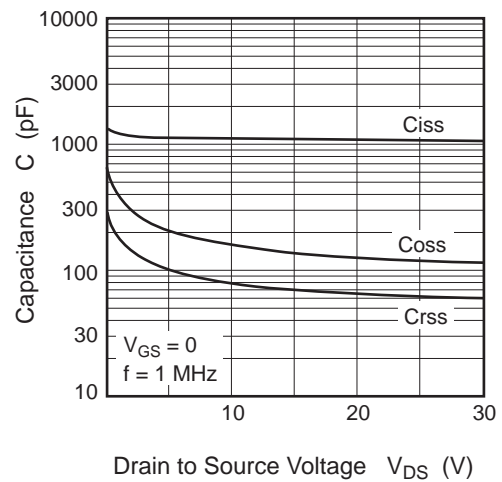
## Main Characteristics



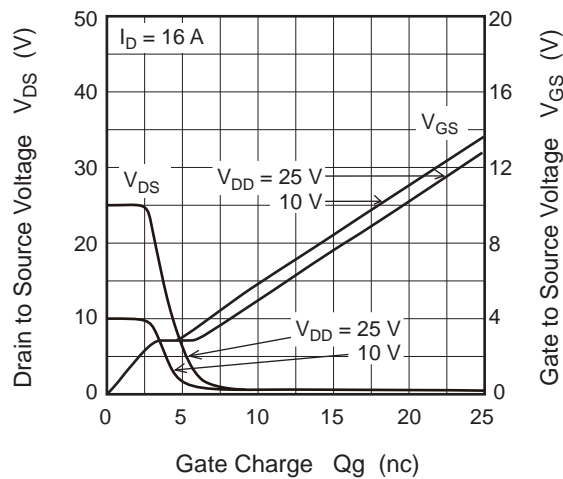
Static Drain to Source on State Resistance vs. Temperature



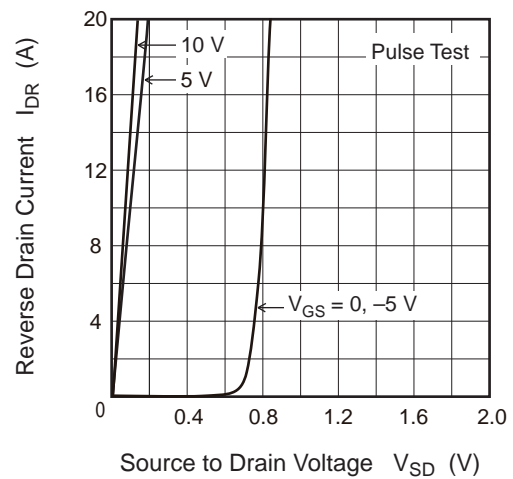
Typical Capacitance vs. Drain to Source Voltage



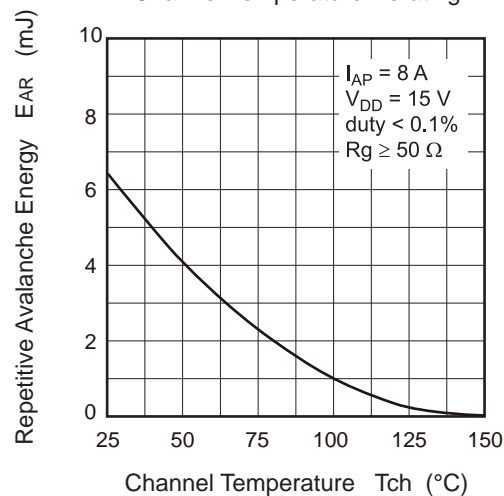
Dynamic Input Characteristics



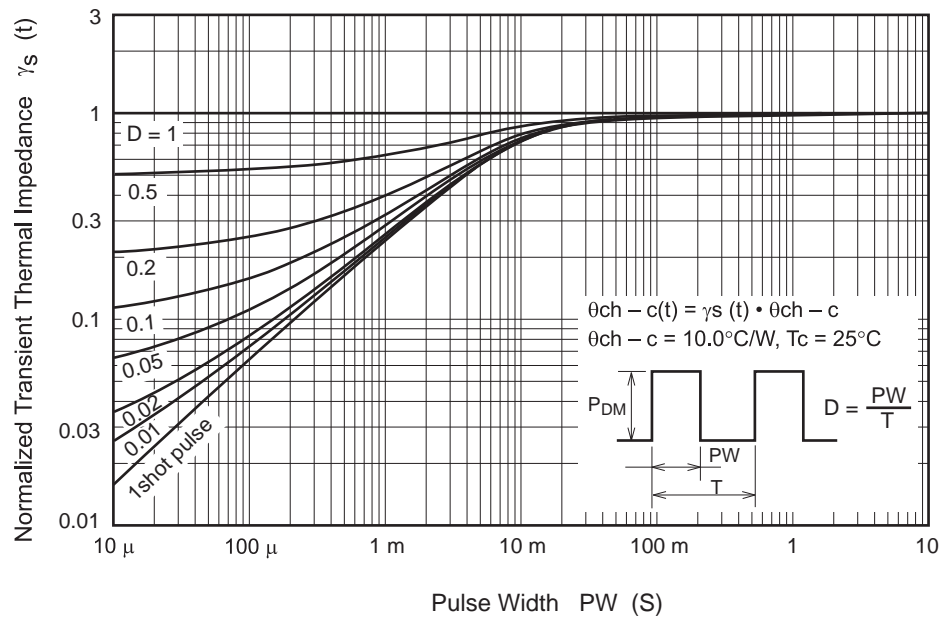
Reverse Drain Current vs. Source to Drain Voltage



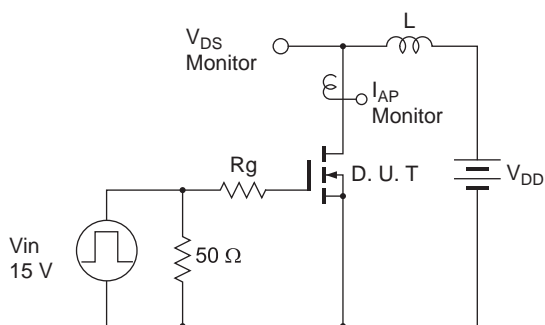
Maximum Avalanche Energy vs. Channel Temperature Derating



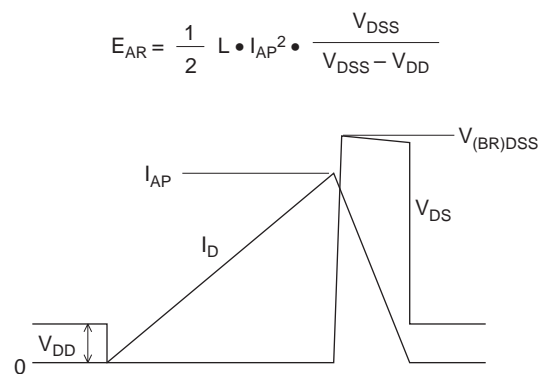
Normalized Transient Thermal Impedance vs. Pulse Width



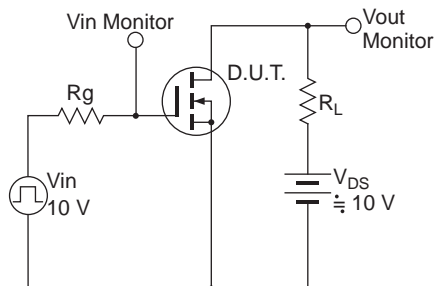
Avalanche Test Circuit



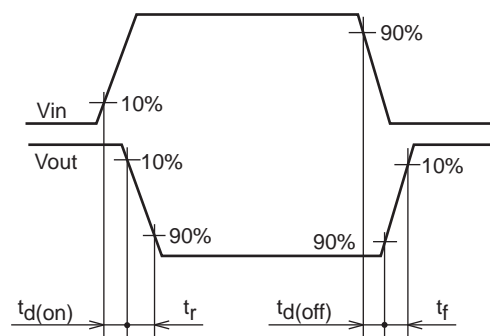
Avalanche Waveform



Switching Time Test Circuit

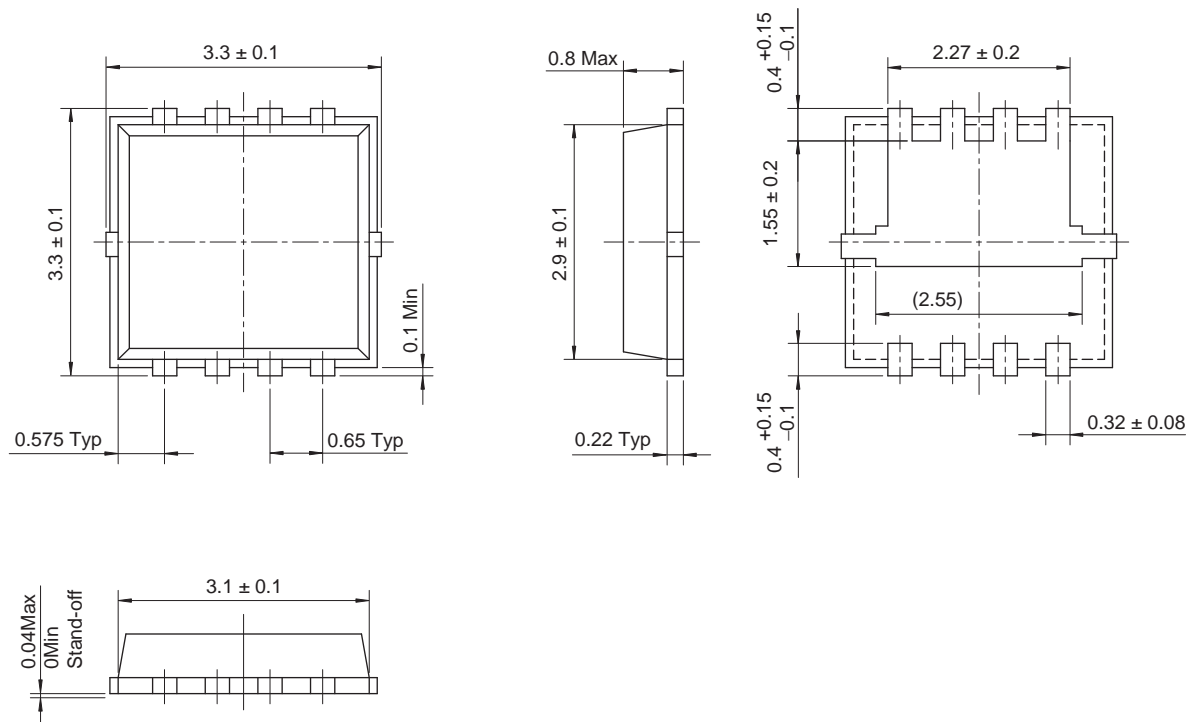


Switching Time Waveform



## Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
HWS0N-8	P-HWS0N8-2.9x3.1-0.65	PWSN0008JB-A	—	0.022g



## Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK03E2DNS-00-J5	5000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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**Renesas Electronics Canada Limited**  
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada  
Tel: +1-905-898-5441, Fax: +1-905-898-3220

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Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.  
Tel: +44-1628-585-100, Fax: +44-1628-585-900

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-65030, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
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Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

**Renesas Electronics Korea Co., Ltd.**  
11F., Samik Laviel' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5141